



SLLS174G-FEBRUARY 1994-REVISED APRIL 2009

SN55LBC180 SN65LBC180

SN75LBC180

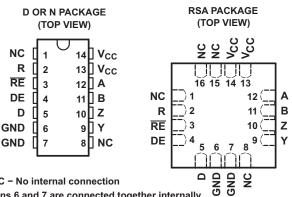
# LOW-POWER RS-485 LINE DRIVER AND RECEIVER PAIRS

### FEATURES

- Designed for High-Speed Multipoint Data Transmission Over Long Cables
- Operate With Pulse Durations as Low as 30 ns
- Low Supply Current . . . 5 mA Max •
- Meet or Exceed the Requirements of ANSI . Standard RS-485 and ISO 8482:1987(E)
- 3-State Outputs for Party-Line Buses
- Common-Mode Voltage Range of –7 V to 12 V •
- **Thermal Shutdown Protection Prevents Driver Damage From Bus Contention**
- Positive and Negative Output Current Limiting
- Pin Compatible With the SN75ALS180

### DESCRIPTION

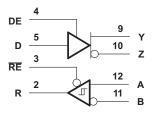
The SN55LBC180, SN65LBC180 and SN75LBC180 differential driver and receiver pairs are monolithic integrated circuits designed for bidirectional data communication over long cables that take on the characteristics of transmission lines. They are balanced, or differential, voltage mode devices that meet or exceed the requirements of industry standards ANSI RS-485 and ISO 8482:1987(E). These devices are designed using TI's proprietary LinBiCMOS<sup>™</sup> with the low-power consumption of CMOS and the precision and robustness of bipolar transistors in the same circuit.



NC - No internal connection

Pins 6 and 7 are connected together internally Pins 13 and 14 are connected together internally

logic diagram (positive logic)



| T <sub>A</sub> | PACKAGE | PART NUMBER   | PART MARKING |  |  |  |  |  |  |  |
|----------------|---------|---------------|--------------|--|--|--|--|--|--|--|
|                | PDIP    | SN75LBC180N   | SN75LBC180N  |  |  |  |  |  |  |  |
| 0°C to 70°C    | SOIC    | SN75LBC180D   | 7LB180       |  |  |  |  |  |  |  |
|                | QFN     | SN75LBC180RSA | LB180        |  |  |  |  |  |  |  |
|                | PDIP    | SN65LBC180N   | 65LBC180N    |  |  |  |  |  |  |  |
| -40°C to 85°C  | SOIC    | SN65LBC180D   | 6LB180       |  |  |  |  |  |  |  |
|                | QFN     | SN65LBC180RSA | BL180        |  |  |  |  |  |  |  |
| -55°C to 125°C | QFN     | SN55LBC180RSA | SN55LBC180   |  |  |  |  |  |  |  |

### **ORDERING INFORMATION**



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. LinBiCMOS is a trademark of Texas Instruments.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### **DESCRIPTION (CONTINUED)**

The SN55LBC180, SN65LBC180 and SN75LBC180 combine a differential line driver and receiver with 3-state outputs and operate from a single 5-V supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected to function as a direction control. The driver differential outputs and the receiver differential inputs are connected to separate terminals for full-duplex operation and are designed to present minimum loading to the bus whether disabled or powered off ( $V_{CC} = 0$ ). These parts feature a wide common-mode voltage range making them suitable for point-to-point or multipoint data-bus applications.

The devices also provide positive and negative output-current limiting and thermal shutdown for protection from line fault conditions. The line driver shuts down at a junction temperature of approximately 172°C.

The SN75LBC180 is characterized for operation over the commercial temperature range of 0°C to 70°C. The SN65LBC180 is characterized over the industrial temperature range of –40°C to 85°C.

The SN55LBC180 is characterized for operation over the military temperature range of -55°C to 125°C.

| DRIVER  |                       |           |     |  |  |  |  |  |  |  |
|---|-----------------------|-----------|-----|--|--|--|--|--|--|--|
| INPUT   | ENABLE                | OUTP      | UTS |  |  |  |  |  |  |  |
| D   | DE                    | Y         | Z   |  |  |  |  |  |  |  |
| Н   | Н                     | Н         | L   |  |  |  |  |  |  |  |
| L   | н                     | L         | Н   |  |  |  |  |  |  |  |
| X   | L                     | Z         | Z   |  |  |  |  |  |  |  |
| RECEIVER  |                       |           |     |  |  |  |  |  |  |  |
| DIFFERENTIAL INPUTS<br>A-B                              | EN <u>AB</u> LE<br>RE | OUTF<br>R | TUY |  |  |  |  |  |  |  |
| V <sub>ID</sub> ≥ 0.2 V                                 | L                     | Н         |     |  |  |  |  |  |  |  |
| $-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 \text{ V}$ | L                     | ?         |     |  |  |  |  |  |  |  |
| $V_{ID} \le -0.2 V$                                     | L                     | L         |     |  |  |  |  |  |  |  |
| Х   | Н                     | Z         |     |  |  |  |  |  |  |  |
| Open circuit  | L                     | Н         |     |  |  |  |  |  |  |  |

#### **FUNCTION TABLES**<sup>(1)</sup>

 (1) H = high level, L = low level, ? = Indeterminate, X = irrelevant, Z = high impedance (off)

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### **ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

|                  |                            |   |                               | UNIT |  |  |  |
|------------------|----------------------------|---|-------------------------------|------|--|--|--|
| V <sub>CC</sub>  | Supply voltage range (2)   |   | –0.3 to 7                     |      |  |  |  |
| V <sub>BUS</sub> | Bus voltage range (A, B,   | Y, Z) <sup>(2)</sup>  | -10 to 15                     |      |  |  |  |
|                  | Voltage range at D, R, DI  | $e$ (A, B, Y, Z) $-10$ to 15D, R, DE, $\overline{RE}^{(2)}$ $-0.3$ to $V_{CC}$ + 0.5power dissipationInternally limitpationSee Dissipation Rateure range $-65$ to 150urrent range $-50$ to 50 | -0.3 to V <sub>CC</sub> + 0.5 | V    |  |  |  |
|                  | Continuous total power di  | ssipation <sup>(3)</sup>  | Internally limited            |      |  |  |  |
|                  | Total power dissipation    |   | See Dissipation Rating Table  |      |  |  |  |
| T <sub>stg</sub> | Storage temperature rang   | je  | -65 to 150                    |      |  |  |  |
| I <sub>O</sub>   | Receiver output current ra | ange  | -50 to 50                     | mA   |  |  |  |
|                  |                            | HBM (Human Body Model) EIA/JESD22-A114  | ±4                            | kV   |  |  |  |
| ESD              | Electrostatic discharge    | MM (Machine Model) EIA/JESD22-A115  | 400                           | V    |  |  |  |
|                  |                            | CDM (Charge Device Model) EIA/JESD22-C101   | 1.5                           | kV   |  |  |  |

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to GND.

(3) The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.

### **DISSIPATION RATING TABLE**

| PACKAGE <sup>(1)</sup> | T <sub>A</sub> ≤ 25°C<br>POWER RATING | DERATING FACTOR<br>ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C<br>POWER RATING | T <sub>A</sub> = 85°C<br>POWER RATING | T <sub>A</sub> = 125°C<br>POWER RATING |
|------------------------|---------------------------------------|--|---------------------------------------|---------------------------------------|--|
| D                      | 950 mW                                | 7.6 mW/°C                                      | 608 mW                                | 494 mW                                | _                                      |
| Ν                      | 1150 mW                               | 9.2 mW/°C                                      | 736 mW                                | 598 mW                                | _                                      |
| RSA                    | 3333 mW                               | 26.67 mW/°C                                    | 2133 mW                               | 1733 mW                               | 400 mW                                 |

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

### **RECOMMENDED OPERATING CONDITIONS**

|                                    |   |               | MIN               | NOM | MAX  | UNIT  |  |
|------------------------------------|---|---------------|-------------------|-----|------|-------|--|
| V <sub>CC</sub>                    | Supply voltage  |               | 4.75              | 5   | 5.25 | V     |  |
| V <sub>IH</sub>                    | High-level input voltage                                | D, DE, and RE | 2                 |     |      | V     |  |
| V <sub>IL</sub>                    | Low-level input voltage                                 | D, DE, and RE |                   |     | 0.8  | V     |  |
| V <sub>ID</sub>                    | Differential input voltage                              |               | -6 <sup>(1)</sup> |     | 6    | V     |  |
| $V_{O}, V_{I}, \text{ or } V_{IC}$ | Voltage at any bus terminal (separately or common mode) | A, B, Y, or Z | -7 <sup>(1)</sup> |     | 12   | V     |  |
|                                    | link lavel avte devenant                                | Y or Z        |                   |     | -60  | A     |  |
| I <sub>OH</sub>                    | High-level output current                               | R             |                   |     | -8   | -8 mA |  |
| 1                                  |   | Y or Z        |                   |     | 60   | ~^^   |  |
| IOL                                | Low-level output current                                | R             |                   |     | 8    | 8 mA  |  |
|                                    |   | SN55LBC180    | -55               |     | 125  |       |  |
| T <sub>A</sub>                     | Operating free-air temperature                          | SN65LBC180    | -40               |     | 85   | 85 °C |  |
|                                    |   | SN75LBC180    | 0                 |     | 70   | Ì     |  |

(1) The algebraic convention where the least positive (more negative) limit is designated minimum, is used in this data sheet for the differential input voltage, voltage at any bus terminal, operating temperature, input threshold voltage, and common-mode output voltage.



### **DRIVER SECTION**

### **ELECTRICAL CHARACTERISTICS**

over recommended operating conditions (unless otherwise noted)

|                    | PARAMETER   | TEST CO   | MIN                  | TYP <sup>(1)</sup> | MAX  | UNIT |    |
|--------------------|---|---|----------------------|--------------------|------|------|----|
| V <sub>IK</sub>    | Input clamp voltage   | I <sub>I</sub> = -18 mA                                 |                      |                    |      | -1.5 | V  |
|                    |   |   | SN55LBC180           | 1                  | 2.5  | 5    |    |
|                    |   | $R_L = 54 \Omega$ ,<br>See Figure 1                     | SN65LBC180           | 1.1                | 2.5  | 5    |    |
|                    | Differential extruct valtage magnitude (2)                        | coo riguro r  | SN75LBC180           | 1.5                | 2.5  | 5    | V  |
| V <sub>OD</sub>    | Differential output voltage magnitude <sup>(2)</sup>              | $R_L = 60 \Omega$ ,<br>See Figure 2                     | SN55LBC180           | 1                  | 2.5  | 5    | v  |
|                    |   |   | SN65LBC180           | 1.1                | 2    | 5    |    |
|                    |   | Coo riguro L  | SN75LBC180           | 1.5                | 2    | 5    |    |
| Δ  V <sub>OD</sub> | Change in magnitude of differential output voltage <sup>(3)</sup> | See Figure 1 and F                                      |                      |                    | ±0.2 | V    |    |
| V <sub>OC</sub>    | Common-mode output voltage  |   |                      | 1                  | 2.5  | 3    | V  |
| Δ  V <sub>OC</sub> | Change in magnitude of common-mode output voltage <sup>(3)</sup>  | $R_L = 54 \Omega,$                                      | See Figure 1         |                    |      | ±0.2 | V  |
| lo                 | Output current with power off                                     | $V_{CC} = 0,$   | $V_0 = -7 V$ to 12 V |                    |      | ±100 | μΑ |
| I <sub>OZ</sub>    | High-impedance-state output current                               | $V_0 = -7$ V to 12 V                                    |                      |                    |      | ±100 | μΑ |
| I <sub>IH</sub>    | High-level input current  | V <sub>I</sub> = 2.4 V                                  |                      |                    |      | 100  | μΑ |
| IIL                | Low-level input current   | $V_{I} = 0.4 V$   |                      |                    |      | 100  | μA |
| I <sub>OS</sub>    | Short-circuit output current                                      | $-7 \text{ V} \le \text{V}_{\text{O}} \le 12 \text{ V}$ |                      |                    |      | ±250 | mA |
|                    | Supply surront  | Receiver disabled                                       | Outputs enabled      |                    |      | 5    | mA |
| I <sub>CC</sub>    | Supply current  |   | Outputs disabled     |                    |      | 3    | ШA |

(1) All typical values are at  $V_{CC}$  = 5 V and  $T_A$  = 25°C.

The minimum V<sub>OD</sub> specification may not fully comply with ANSI RS-485 at operating temperatures below 0°C. System designers should (2)

take the possibly lower output signal into account in determining the maximum signal-transmission distance.  $\Delta |V_{OD}|$  and  $\Delta |V_{OC}|$  are the changes in the steady-state magnitude of  $V_{OD}$  and  $V_{OC}$ , respectively, that occur when the input is changed (3) from a high level to a low level.

### SWITCHING CHARACTERISTICS

 $V_{CC} = 5 \text{ V}, \text{ } \text{T}_{A} = 25^{\circ}\text{C}$ 

|                    | PARAMETER                           | TEST                    | TEST CONDITIONS |   |    | MAX | UNIT |
|--------------------|-------------------------------------|-------------------------|-----------------|---|----|-----|------|
| t <sub>d(OD)</sub> | Differential output delay time      | P - 54 0                | Soo Figuro 2    | 7 | 12 | 18  | ns   |
| t <sub>t(OD)</sub> | Differential output transition time | $R_L = 54 \Omega,$      | See Figure 3    | 5 | 10 | 20  | ns   |
| t <sub>PZH</sub>   | Output enable time to high level    | $R_L = 110 \Omega$ ,    | See Figure 4    |   |    | 35  | ns   |
| t <sub>PZL</sub>   | Output enable time to low level     | R <sub>L</sub> = 110 Ω, | See Figure 5    |   |    | 35  | ns   |
| t <sub>PHZ</sub>   | Output disable time from high level | $R_L = 110 \Omega$ ,    | See Figure 4    |   |    | 50  | ns   |
| t <sub>PLZ</sub>   | Output disable time from low level  | $R_L = 110 \Omega$ ,    | See Figure 5    |   |    | 35  | ns   |

### SWITCHING CHARACTERISTICS (SN55LBC180)

 $V_{CC} = 5 \text{ V}, \text{ } \text{T}_{A} = 25^{\circ}\text{C}$ 

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|                    | PARAMETER                           | TEST                    | CONDITIONS   | MIN TYP | MAX | UNIT |  |
|--------------------|-------------------------------------|-------------------------|--------------|---------|-----|------|--|
| t <sub>d(OD)</sub> | Differential output delay time      | D 54.0                  | See Figure 2 | 15      |     | ns   |  |
| t <sub>t(OD)</sub> | Differential output transition time | R <sub>L</sub> = 54 Ω,  | See Figure 3 | 21      |     | ns   |  |
| t <sub>PZH</sub>   | Output enable time to high level    | D 110 0                 | See Figure 4 | 32      |     | ~~   |  |
| t <sub>PHZ</sub>   | Output disable time from high level | R <sub>L</sub> = 110 Ω, | See Figure 4 | 55      |     | ns   |  |
| t <sub>PZL</sub>   | Output enable time to low level     | D 110 0                 | Soo Figuro F | 32      |     |      |  |
| t <sub>PLZ</sub>   | Output disable time from low level  | R <sub>L</sub> = 110 Ω, | See Figure 5 | 20      |     | ns   |  |



### **RECEIVER SECTION**

### **ELECTRICAL CHARACTERISTICS**

over recommended operating conditions (unless otherwise noted)

|                  | PARAMETER   | TEST CO                                       | NDITIONS                | MIN  | TYP  | MAX | UNIT |
|------------------|---|---|-------------------------|------|------|-----|------|
| $V_{IT+}$        | Positive-going input threshold voltage                    | I <sub>O</sub> = -8 mA                        |                         |      |      | 0.2 | V    |
| $V_{\text{IT}-}$ | Negative-going input threshold voltage                    | I <sub>O</sub> = 8 mA                         |                         | -0.2 |      |     | V    |
| $V_{\text{hys}}$ | Hysteresis voltage (V <sub>IT+</sub> – V <sub>IT–</sub> ) |   |                         |      | 45   |     | mV   |
| V <sub>IK</sub>  | Enable-input clamp voltage                                | I <sub>I</sub> = -18 mA                       |                         | -1.5 |      |     | V    |
| V <sub>OH</sub>  | High-level output voltage                                 | V <sub>ID</sub> = 200 mV,                     | I <sub>OH</sub> = -8 mA | 3.5  | 4.5  |     | V    |
| V <sub>OL</sub>  | Low-level output voltage                                  | $V_{ID} = -200 \text{ mV},$                   | I <sub>OL</sub> = 8 mA  |      | 0.3  | 0.5 | V    |
| I <sub>OZ</sub>  | High-impedance-state output current                       | $V_{O} = 0 V$ to $V_{CC}$                     |                         |      |      | ±20 | μΑ   |
| I <sub>IH</sub>  | High-level enable-input current                           | V <sub>IH</sub> = 2.4 V                       |                         | -50  |      |     | А    |
| IIL              | Low-level enable-input current                            | V <sub>IL</sub> = 0.4 V                       |                         | -100 |      |     | μΑ   |
|                  |   | $V_{I} = 12 V, V_{CC} = 5 V,$                 | Other input at 0 V      |      | 0.7  | 1   |      |
|                  |   | V <sub>I</sub> = 12 V, V <sub>CC</sub> = 0 V, | Other input at 0 V      |      | 0.8  | 1   |      |
| II               | Bus input current   | $V_{I} = -7 V, V_{CC} = 5 V,$                 | Other input at 0 V      | -0.8 | -0.5 |     | mA   |
|                  |   | $V_{I} = -7 V, V_{CC} = 0 V,$                 | Other input at 0 V      | -0.8 | -0.5 |     |      |
|                  | Current current   | Driver dischlad                               | Outputs enabled         |      |      | 5   |      |
| I <sub>CC</sub>  | Supply current  | Driver disabled                               | Outputs disabled        |      |      | 3   | mA   |

### SWITCHING CHARACTERISTICS

 $V_{CC} = 5 V, T_A = 25^{\circ}C$ 

|                    | PARAMETER  | TEST COND                                | MIN | TYP | MAX | UNIT |    |
|--------------------|--|--|-----|-----|-----|------|----|
| t <sub>PHL</sub>   | Propagation delay time, high- to low-level output    |  |     | 11  | 22  | 33   | ns |
| t <sub>PLH</sub>   | Propagation delay time, low- to high-level output    |  |     | 11  | 22  | 33   | ns |
| t <sub>sk(p)</sub> | Pulse skew (  t <sub>PHL</sub> – t <sub>PLH</sub>  ) | $V_{ID} = -1.5$ V to 1.5 V, See Figure 6 |     |     | 3   | 6    | ns |
| t <sub>t</sub>     | Transition time                                      |  |     |     | 5   | 8    | ns |
| t <sub>PZH</sub>   | Output enable time to high level                     |  |     |     |     | 35   | ns |
| t <sub>PZL</sub>   | Output enable time to low level                      |  |     |     |     | 30   | ns |
| t <sub>PHZ</sub>   | Output disable time from high level                  | See Figure 7                             |     |     |     | 35   | ns |
| t <sub>PLZ</sub>   | Output disable time from low level                   |  |     |     | 30  | ns   |    |

### SWITCHING CHARACTERISTICS (SN55LBC180)

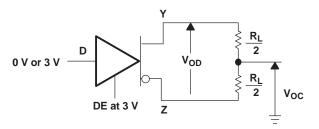
 $V_{CC} = 5 \text{ V}, \text{ } \text{T}_{A} = 25^{\circ}\text{C}$ 

|                     | PARAMETER  | TEST CONDIT                              | IONS         | MIN TYP | MAX | UNIT |
|---------------------|--|--|--------------|---------|-----|------|
| t <sub>PHL</sub>    | Propagation delay time, high- to low-level output    |  |              | 26      |     | ns   |
| t <sub>PLH</sub>    | Propagation delay time, low- to high-level output    | 1 = 15  to $15$                          | Soo Figuro 6 | 23      |     | ns   |
| t <sub>sk(p)</sub>  | Pulse skew (  t <sub>PHL</sub> – t <sub>PLH</sub>  ) | $V_{ID} = -1.5$ V to 1.5 V, See Figure 6 |              | 3       |     | ns   |
| t <sub>sk(p)t</sub> | Transition time                                      |  |              | 4       |     | ns   |
| t <sub>PZH</sub>    | Output enable time to high level                     |  |              | 30      |     | ns   |
| t <sub>PHZ</sub>    | Output disable time from high level                  |  |              | 26      |     | ns   |
| t <sub>PZL</sub>    | Output enable time to low level                      | See Figure 4                             |              | 30      |     | ns   |
| t <sub>PLZ</sub>    | Output disable time from low level                   |  |              | 30      |     | ns   |

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### PARAMETER MEASUREMENT INFORMATION





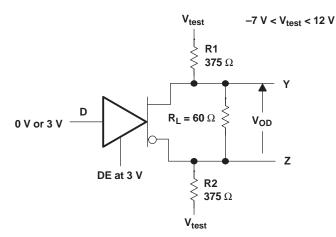
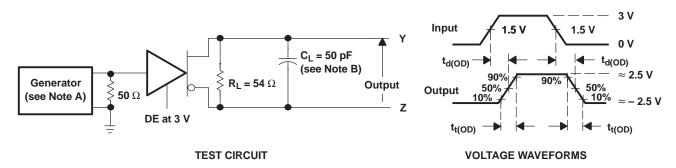


Figure 2. Driver V<sub>OD</sub> Test Circuit

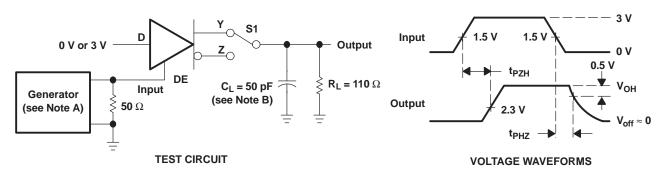


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR > 1 MHz, 50% duty cycle,  $t_r \le 6$  ns,  $t_f \le 6$  ns,  $Z_O = 50 \Omega$ .
  - B. C<sub>L</sub> includes probe and jig capacitance.

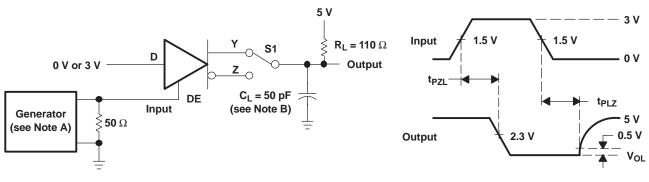
#### Figure 3. Driver Test Circuit and Differential Output Delay and Transition Time Voltage Waveforms







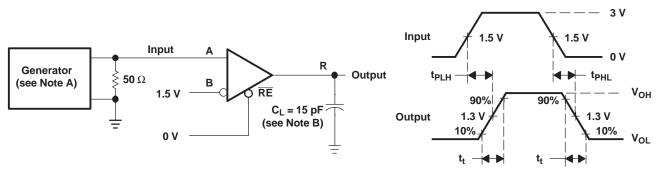




**TEST CIRCUIT** 

VOLTAGE WAVEFORMS

Figure 5. Driver Test Circuit and Enable and Disable Time Voltage Waveforms



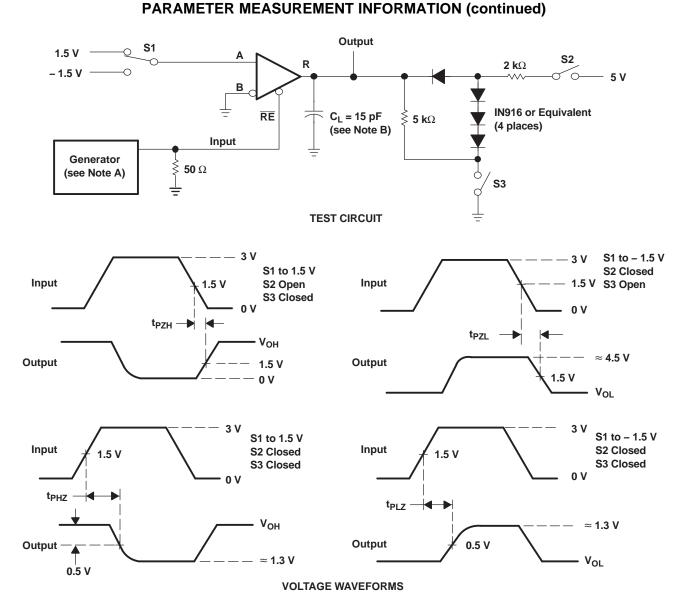
**TEST CIRCUIT** 

VOLTAGE WAVEFORMS

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle, t<sub>r</sub>  $\leq$  6 ns, t<sub>f</sub>  $\leq$  6 ns, Z<sub>O</sub> = 50  $\Omega$ .
  - B.  $C_L$  includes probe and jig capacitance.

Figure 6. Receiver Test Circuit and Propagation Delay Time Voltage Waveforms





# NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR $\leq$ 1 MHz, 50% duty cycle, t<sub>r</sub> $\leq$ 6 ns, t<sub>f</sub> $\leq$ 6 ns, Z<sub>O</sub> = 50 $\Omega$ .

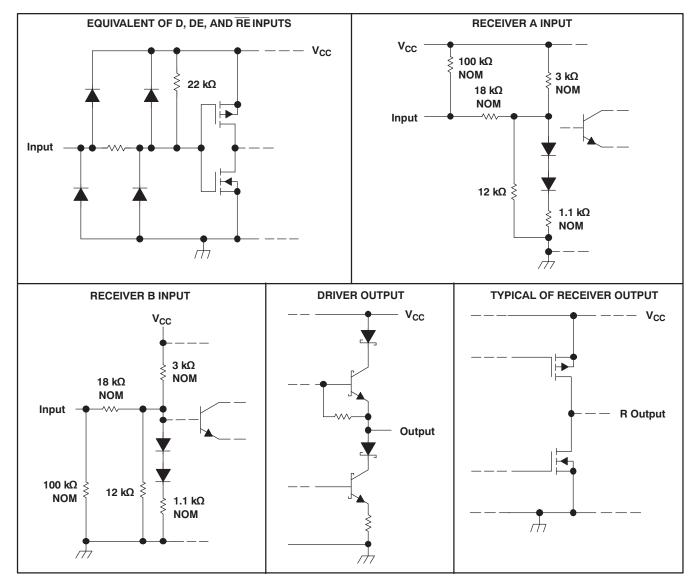
B. C<sub>L</sub> includes probe and jig capacitance.

### Figure 7. Receiver Output Enable and Disable Times



### **TYPICAL CHARACTERISTICS**

### SCHEMATICS OF INPUTS AND OUTPUTS

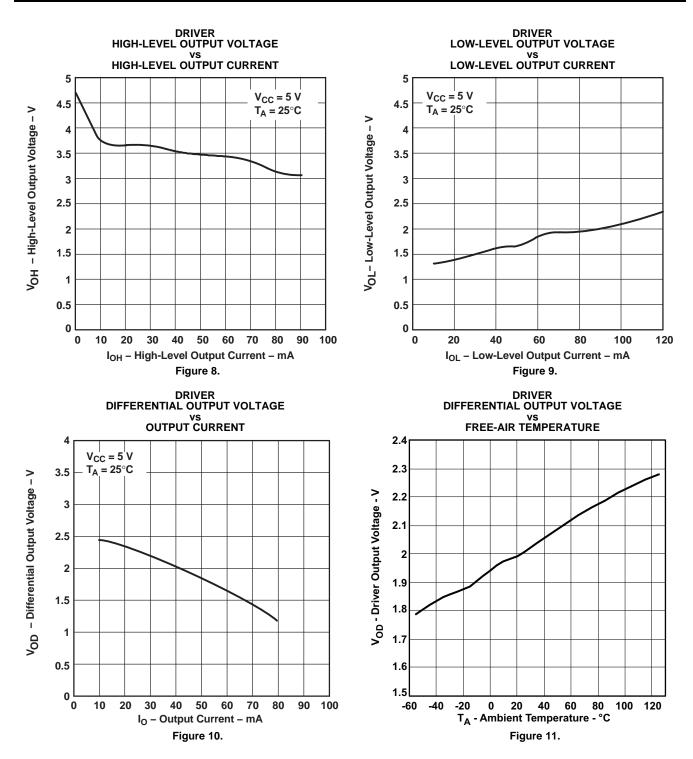


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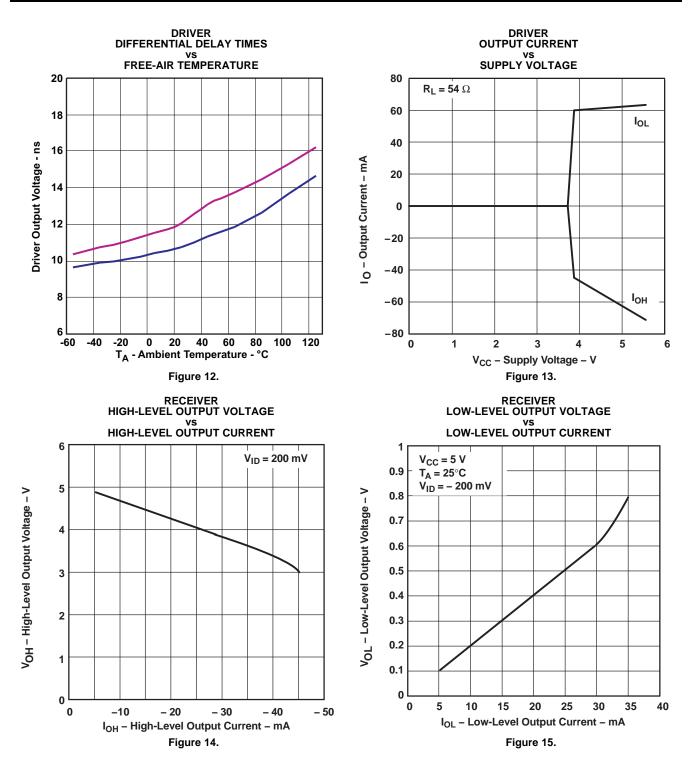


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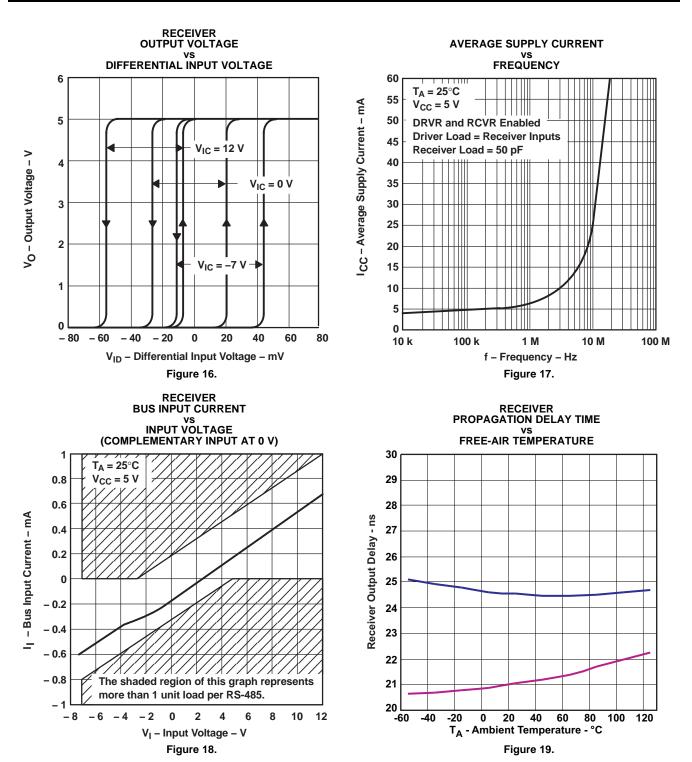




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### **APPLICATION INFORMATION**

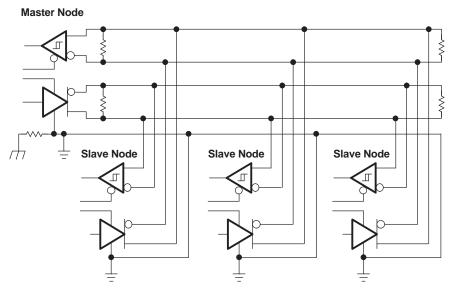


Figure 20. Full Duplex Application Circuit



10-Dec-2020

### **PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| SN55LBC180RSAR   | ACTIVE        | QFN          | RSA                | 16   | 3000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | SN55<br>LBC180          | Samples |
| SN55LBC180RSAT   | ACTIVE        | QFN          | RSA                | 16   | 250            | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | SN55<br>LBC180          | Samples |
| SN65LBC180D      | ACTIVE        | SOIC         | D                  | 14   | 50             | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 85    | 6LB180                  | Samples |
| SN65LBC180DR     | ACTIVE        | SOIC         | D                  | 14   | 2500           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 85    | 6LB180                  | Samples |
| SN65LBC180DRG4   | ACTIVE        | SOIC         | D                  | 14   | 2500           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 85    | 6LB180                  | Samples |
| SN65LBC180N      | ACTIVE        | PDIP         | Ν                  | 14   | 25             | RoHS & Green    | NIPDAU                               | N / A for Pkg Type   | -40 to 85    | SN65LBC180N             | Samples |
| SN65LBC180RSAR   | ACTIVE        | QFN          | RSA                | 16   | 3000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -40 to 85    | BL180                   | Samples |
| SN65LBC180RSAT   | ACTIVE        | QFN          | RSA                | 16   | 250            | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -40 to 85    | BL180                   | Samples |
| SN65LBC180RSATG4 | ACTIVE        | QFN          | RSA                | 16   | 250            | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -40 to 85    | BL180                   | Samples |
| SN75LBC180D      | ACTIVE        | SOIC         | D                  | 14   | 50             | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | 0 to 70      | 7LB180                  | Samples |
| SN75LBC180DG4    | ACTIVE        | SOIC         | D                  | 14   | 50             | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | 0 to 70      | 7LB180                  | Samples |
| SN75LBC180DR     | ACTIVE        | SOIC         | D                  | 14   | 2500           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | 0 to 70      | 7LB180                  | Samples |
| SN75LBC180DRG4   | ACTIVE        | SOIC         | D                  | 14   | 2500           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | 0 to 70      | 7LB180                  | Samples |
| SN75LBC180N      | ACTIVE        | PDIP         | Ν                  | 14   | 25             | RoHS & Green    | NIPDAU                               | N / A for Pkg Type   | 0 to 70      | SN75LBC180N             | Samples |
| SN75LBC180RSAT   | ACTIVE        | QFN          | RSA                | 16   | 250            | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | 0 to 70      | LB180                   | Samples |

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.



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<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN55LBC180, SN65LBC180, SN75LBC180 :

- Catalog: SN75LBC180
- Automotive: SN65LBC180-Q1
- Military: SN55LBC180

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects



## PACKAGE OPTION ADDENDUM

10-Dec-2020

Military - QML certified for Military and Defense Applications

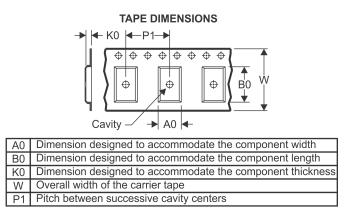
# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



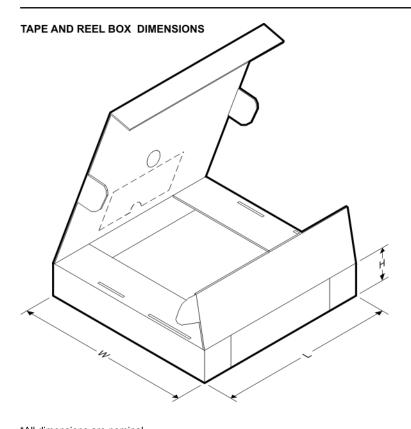
| *All dimensions are nominal |                 |                    |    |      |                          |                          |            |            |            |            |           |                  |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                      | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| SN55LBC180RSAR              | QFN             | RSA                | 16 | 3000 | 330.0                    | 12.4                     | 4.25       | 4.25       | 1.15       | 8.0        | 12.0      | Q2               |
| SN55LBC180RSAT              | QFN             | RSA                | 16 | 250  | 180.0                    | 12.4                     | 4.25       | 4.25       | 1.15       | 8.0        | 12.0      | Q2               |
| SN65LBC180DR                | SOIC            | D                  | 14 | 2500 | 330.0                    | 16.4                     | 6.5        | 9.0        | 2.1        | 8.0        | 16.0      | Q1               |
| SN65LBC180RSAR              | QFN             | RSA                | 16 | 3000 | 330.0                    | 12.4                     | 4.35       | 4.35       | 1.1        | 8.0        | 12.0      | Q2               |
| SN65LBC180RSAR              | QFN             | RSA                | 16 | 3000 | 330.0                    | 12.4                     | 4.25       | 4.25       | 1.15       | 8.0        | 12.0      | Q2               |
| SN65LBC180RSAT              | QFN             | RSA                | 16 | 250  | 180.0                    | 12.4                     | 4.25       | 4.25       | 1.15       | 8.0        | 12.0      | Q2               |
| SN65LBC180RSAT              | QFN             | RSA                | 16 | 250  | 330.0                    | 12.5                     | 4.35       | 4.35       | 1.1        | 8.0        | 12.0      | Q2               |
| SN75LBC180DR                | SOIC            | D                  | 14 | 2500 | 330.0                    | 16.4                     | 6.5        | 9.0        | 2.1        | 8.0        | 16.0      | Q1               |
| SN75LBC180RSAT              | QFN             | RSA                | 16 | 250  | 180.0                    | 12.4                     | 4.25       | 4.25       | 1.15       | 8.0        | 12.0      | Q2               |

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# PACKAGE MATERIALS INFORMATION

6-Nov-2020



| *All dimensions are nominal |              |                 |      |      |             |            |             |
|-----------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device                      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
| SN55LBC180RSAR              | QFN          | RSA             | 16   | 3000 | 853.0       | 449.0      | 35.0        |
| SN55LBC180RSAT              | QFN          | RSA             | 16   | 250  | 210.0       | 185.0      | 35.0        |
| SN65LBC180DR                | SOIC         | D               | 14   | 2500 | 333.2       | 345.9      | 28.6        |
| SN65LBC180RSAR              | QFN          | RSA             | 16   | 3000 | 338.0       | 355.0      | 50.0        |
| SN65LBC180RSAR              | QFN          | RSA             | 16   | 3000 | 853.0       | 449.0      | 35.0        |
| SN65LBC180RSAT              | QFN          | RSA             | 16   | 250  | 210.0       | 185.0      | 35.0        |
| SN65LBC180RSAT              | QFN          | RSA             | 16   | 250  | 338.0       | 355.0      | 50.0        |
| SN75LBC180DR                | SOIC         | D               | 14   | 2500 | 333.2       | 345.9      | 28.6        |
| SN75LBC180RSAT              | QFN          | RSA             | 16   | 250  | 210.0       | 185.0      | 35.0        |

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



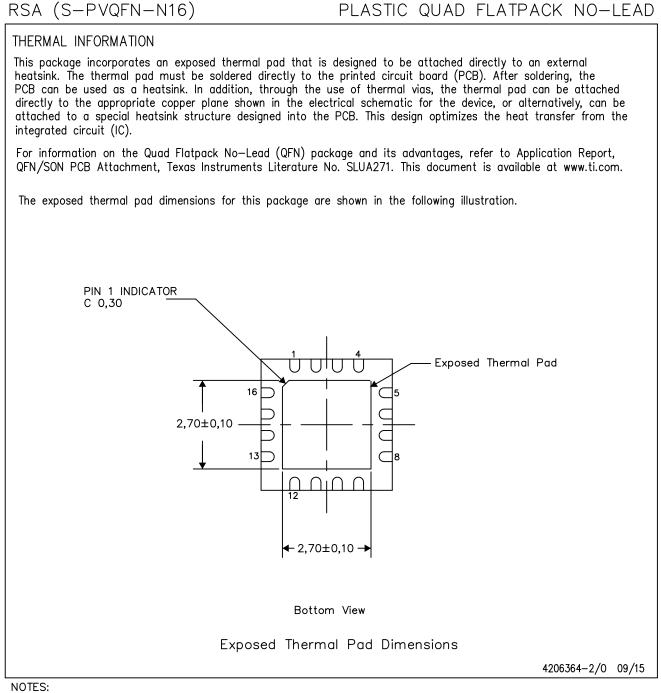
# **MECHANICAL DATA**



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-leads (QFN) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-220.



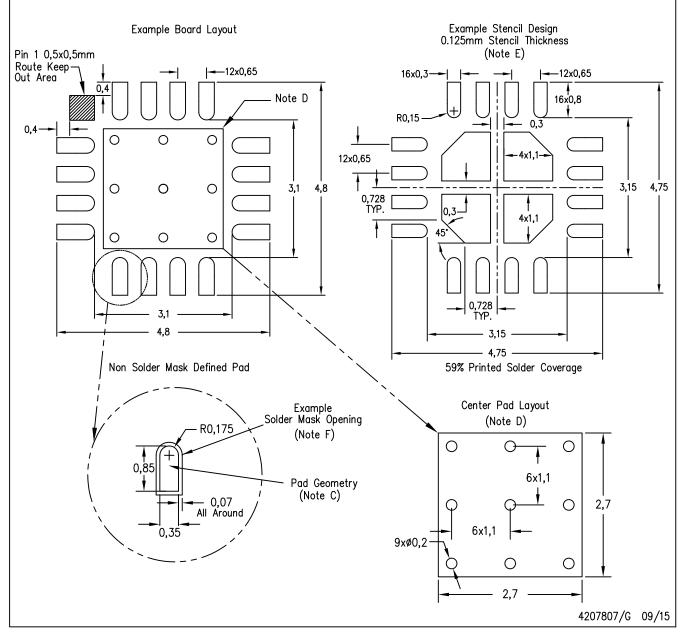


A. All linear dimensions are in millimeters



RSA (S-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="http://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- $\mathsf{F}.$  Customers should contact their board fabrication site for solder mask tolerances.



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